

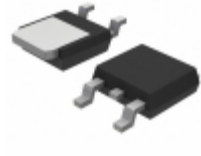
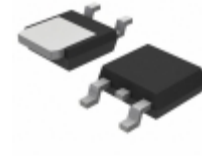


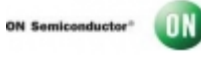

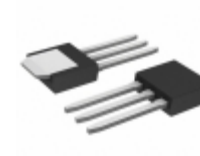
	<h2>NTD5865NT4G</h2>
	<p>Hersteller-Teilenummer: NTD5865NT4G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 43A DPAK</p> <p>Datenblätter:  NTD5865NT4G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 75840 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD5865NT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 43A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	75840 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	71W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	43A (Tc)
Rds On (Max) @ Id, Vgs	18 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1261pF @ 25V
Verpackung	Tape & Reel (TR)



















































NTD5865NT4G ist neu im Original, Suche NTD5865NT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD5865NT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD5865NT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD5865NLT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 46A DPAK</p>	 <p>NTD5865N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 43A DPAK</p>	 <p>NTD5862NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 98A DPAK</p>	 <p>NTD5865NL-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 46A IPAK</p>
 <p>NTD5867NLG ON NTD5867NLG ON</p>	 <p>NTD5867N AMI Semiconductor / ON Semiconductor NTD5867N ON</p>	 <p>NTD5865NL ON NTD5865NL ON</p>	 <p>NTD5867NL-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A IPAK</p>

heiße Teile

Mehr

 NTD5414N	 NTD5414NT4G	 NTD5426NT4G	 NTD5802N	 NTD5802NT4G
 NTD5803N	 NTD5803NT4G	 NTD5804N	 NTD5804NG	 NTD5804NT4G
 NTD5805N	 NTD5805NG	 NTD5805NT4G	 NTD5806N	 NTD5806NG
 NTD5806NT4G	 NTD5807N	 NTD5807NG	 NTD5807NT4G	 NTD5862N
 NTD5862NT4G	 NTD5865N-1G	 NTD5865NL	 NTD5865NL-1G	 NTD5865NLT4G
 NTD5867NL	 NTD5867NL-1G	 NTD5867NLG	 NTD5867NLT4G	 NTD5867NT4G
 NTD60N02KG	 NTD60N02R	 NTD60N02R-001	 NTD60N02R-032	 NTD60N02R-035
 NTD60N02R-1G	 NTD60N02R-1R	 NTD60N02R-35G	 NTD60N02RG	 NTD60N02RG-1G
 NTD60N02RT	 NTD60N02RT4	 NTD60N02RT4G	 NTD60N03RT4G	 NTD60N03T4
 NTD60N03T4G	 NTD6414AN	 NTD6414AN-1G	 NTD6414ANT4G	 NTD6414AUG

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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